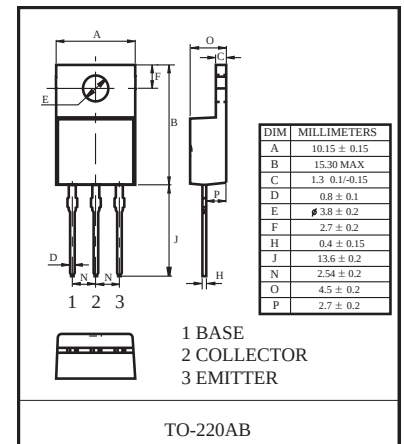


TIP41/41A/41B/41C TRANSISTOR (NPN)

FEATURES

Medium Power Linear Switching Applications



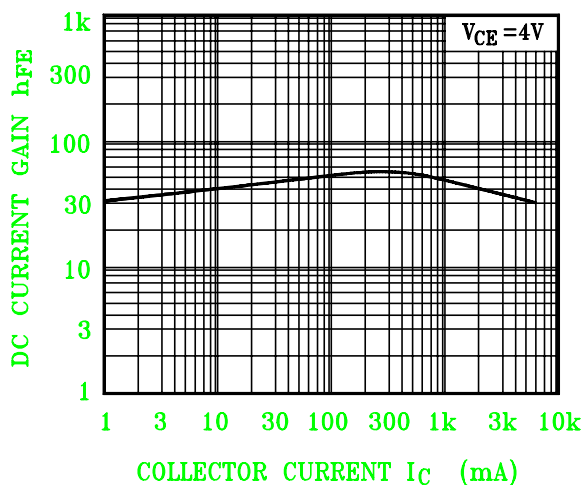
MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	TIP41	TIP41A	TIP41B	TIP41C	Unit
V _{CBO}	Collector-Base Voltage	40	60	80	100	V
V _{CEO}	Collector-Emitter Voltage	40	60	80	100	V
V _{EBO}	Emitter-Base Voltage	5				V
I _C	Collector Current -Continuous	6				A
P _C	Collector Power Dissipation	2				W
T _J	Junction Temperature	150				°C
T _{stg}	Storage Temperature Range	-55to+150				°C

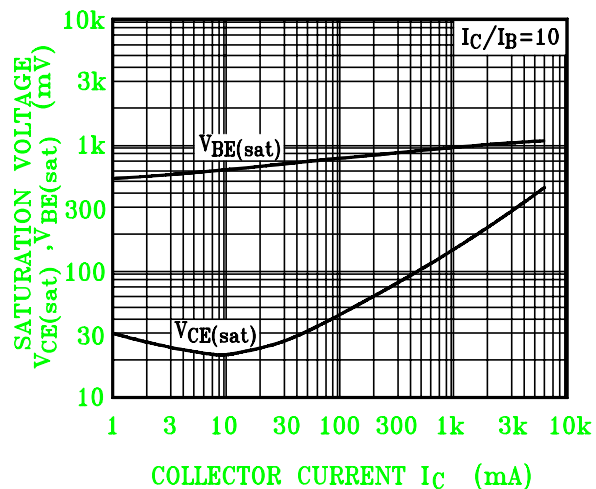
ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	TIP41 TIP41A TIP41B TIP41C V(BR) _{CBO}	I _C = 1mA, I _E =0	40 60 80 100		V
Collector-emitter breakdown voltage	TIP41 TIP41A TIP41B TIP41C V(BR) _{CEO}	I _C = 30mA, I _B =0	40 60 80 100		V
Emitter-base breakdown voltage	V(BR) _{EBO}	I _E = 1mA, I _C =0	5		V
Collector cut-off current	TIP41 TIP41A TIP41B TIP41C I _{CBO}	V _{CB} =40V, I _E =0 V _{CB} =60V, I _E =0 V _{CB} =80V, I _E =0 V _{CB} =100V, I _E =0		0.4	mA
Collector cut-off current	TIP41/41A TIP41B/41C I _{CEO}	V _{CE} = 30V, I _B = 0 V _{CE} = 60V, I _B = 0		0.7	mA
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0		1	mA
DC current gain	h _{FE(1)}	V _{CE} = 4V, I _C = 0.3A	30		
	h _{FE(2)}	V _{CE} =4 V, I _C = 3A	15	75	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =6A, I _B =0.6A		1.5	V
Base-emitter voltage	V _{BE(on)}	V _{CE} = 4V, I _C =6A		2	V
Transition frequency	f _T	V _{CE} =10V , I _C =0.5A f =1MHz	3		MHz

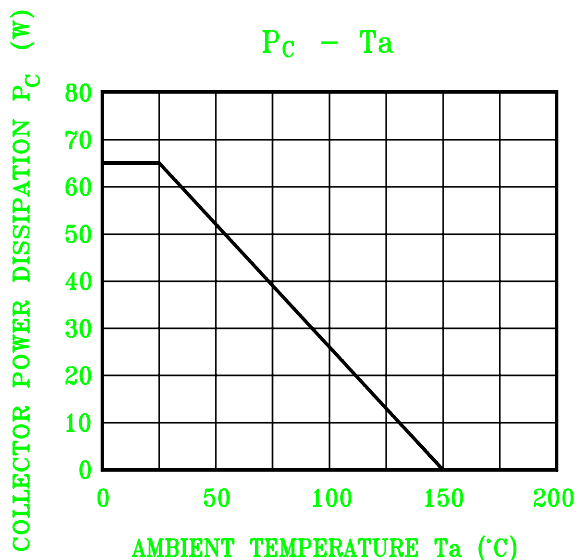
$h_{FE} - I_C$



$V_{CE(sat)}, V_{BE(sat)} - I_C$



$P_C - T_a$



SAFE OPERATING AREA

